

## TS5A3157 10Ω SPDT Analog Switch

### 1 Features

- Low ON-State Resistance (10Ω)
- Control Inputs are 5V Tolerant
- Low Charge Injection
- Excellent ON-State Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.65V to 5.5V Single-Supply Operation
- Latch-up Performance Exceeds 100mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22:
  - 2000V Human-Body Model (A114-B, Class II)
  - 1000V Charged-Device Model (C101)

### 2 Applications

- Sample-and-Hold Circuits
- Battery-Powered Equipment
- [Audio and video signal routing](#)
- Communication Circuits

### 3 Description

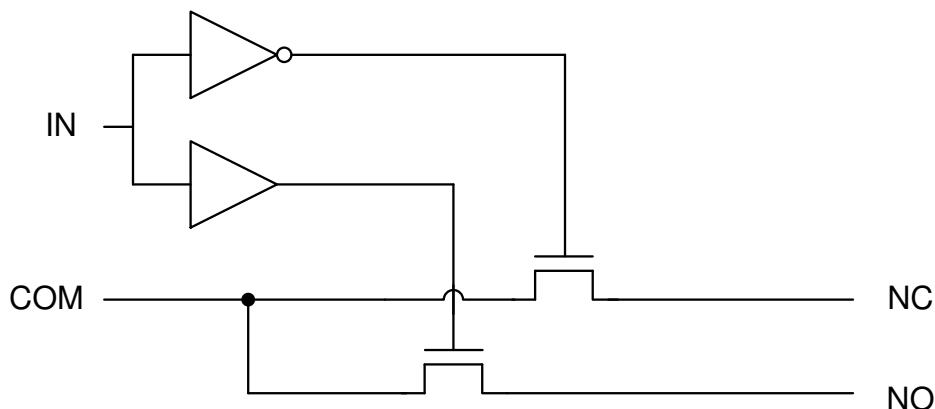
The TS5A3157 device is a single-pole double-throw (SPDT) analog switch that is designed to operate from 1.65V to 5.5V. This device handles both digital and analog signals. Signals up to  $V_+$  can be transmitted in either direction.

#### Package Information

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>
TS5A3157	DBV (SOT-23, 6)	2.9mm × 2.8mm
	DCK (SC70, 6)	2mm × 1.5mm
	YZP (DSBGA, 6)	1.75mm × 1.25mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Functional Block Diagram



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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## 4 Pin Configuration and Functions

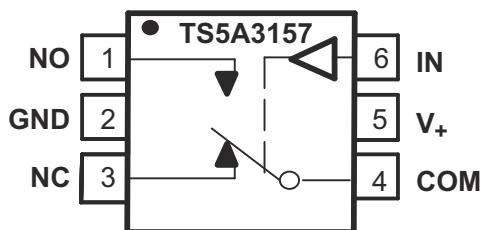


Figure 4-1. DBV and DCK Packages, 6-Pin SOT-23 and SC-70 (Top View)

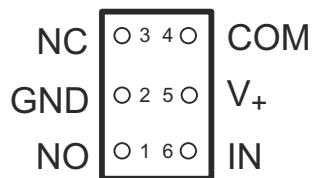


Figure 4-2. YZP Package, 6-Pin DSBGA (Bottom View)

Table 4-1. Pin Functions

PIN		TYPE <sup>(1)</sup>	DESCRIPTION
NO.	NAME		
1	NO	I/O	Normally open switch port
2	GND	—	Ground
3	NC	I/O	Normally closed switch port
4	COM	I/O	Common switch port
5	V+	—	Power supply
6	IN	I	Switch select. High = COM connected to NO; Low = COM connected to NC.

(1) I = input, O = output

## 5 Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(2) (1)</sup>

		MIN	MAX	UNIT
$V_+$	(YZP Only) Supply voltage <sup>(3)</sup>	-0.5	6.5	V
$V_+$	Supply voltage <sup>(3)</sup>	-0.5	6	V
$V_{NO}$ $V_{NC}$ $V_{COM}$	Analog voltage <sup>(3) (4) (5)</sup>	-0.5	$V_+ + 0.5V$	V
$I_K$	Analog port diode current $V_{NO}, V_{NC}, V_{COM} < 0$ or $V_{NO}, V_{NC}, V_{COM} > V_+$	-50	50	mA
$I_{NO}$ $I_{NC}$ $I_{COM}$	On-state switch current $V_{NO}, V_{NC}, V_{COM} = 0$ to $V_+$	-50	50	mA
$V_I$	Digital input voltage <sup>(3) (4)</sup>	-0.5	6	V
$I_{IK}$	Digital input clamp current $V_+ < 0$	-50		mA
$I_+$	Continuous current through $V_+$	-100	100	mA
$I_{GND}$	Continuous current through GND	-100	100	mA
$T_{stg}$	Storage temperature	-65	150	C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

(3) All voltages are with respect to ground unless otherwise specified.

(4) The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

(5) This value is limited to 5.5 V maximum.

### 5.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	$\pm 2000$ V
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 5.3 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TS5A3157			UNIT
		DBV (SOT-23)	DCK (SC70)	YZP (DSBGA)	
		6 PINS	6 PINS	6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	258.2	286.4	132	°C/W
$R_{\theta JC(\text{top})}$	Junction-to-case (top) thermal resistance	182.8	224.6	n/a	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	142.8	143.7	n/a	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	118.4	124.5	n/a	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	142.2	142.8	n/a	°C/W
$R_{\theta JC(\text{bot})}$	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application note.

### 5.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	NOM	MAX	UNIT
$V_{I/O}$	Switch input or output voltage (Max of $V_{CC}$ )	0		$V_+$	V
$V_+$	Supply voltage	1.65		5.5	V
$V_I$	Control input voltage	0		5.5	V
$T_A$	Operating Temperature	-40		85	°C

(1) All unused inputs of the device must be held at VCC or GND to ensure proper device operation. See the TI application report, [Implications of Slow or Floating CMOS Inputs \(SCBA004\)](#)

## 5.5 Electrical Characteristics

$T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS				MIN	TYP	MAX	UNIT	
<b>TS5A3157</b>										
		$V_+ \text{ V}$	$V_{I/O} \text{ V}$	$I_{C OM} \text{ mA}$	$T_A$					
$r_{ON} \text{ (YZP Only)}$	ON-state switch resistance	1.65 V	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$	$I_{C OM} = -4 \text{ mA}$	25°C		140	160	$\Omega$	
					Full			160		
		2.3 V		$I_{C OM} = -8 \text{ mA}$	25°C		35	45		
					Full			50		
		3 V		$I_{C OM} = -24 \text{ mA}$	25°C		12	20		
					Full			20		
				$I_{C OM} = -30 \text{ mA}$	25°C		5.5	10		
					Full			12		
$r_{ON}$	ON-state switch resistance	1.65 V	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$	$I_{C OM} = -4 \text{ mA}$	25°C		140	180	$\Omega$	
					Full			180		
		2.3 V		$I_{C OM} = -8 \text{ mA}$	25°C		35	45		
					Full			50		
		3 V		$I_{C OM} = -24 \text{ mA}$	25°C		12	20		
					Full			20		
				$I_{C OM} = -30 \text{ mA}$	25°C		5.5	12		
					Full			15		
$\Delta r_{ON}$	Maximum ON resistance between any two channels	1.65 V	$V_{NO} \text{ or } V_{NC} = 1.16 \text{ V}$	$I_{C OM} = -4 \text{ mA}$	25°C		0.5	0.6	$\Omega$	
					Full			0.75		
		2.3 V		$I_{C OM} = -8 \text{ mA}$	25°C		0.3	0.5		
					Full			0.7		
		3 V	$V_{NO} \text{ or } V_{NC} = 2.1 \text{ V}$	$I_{C OM} = -24 \text{ mA}$	25°C		0.2	0.4		
					Full			0.4		
		4.5 V	$V_{NO} \text{ or } V_{NC} = 3.15 \text{ V}$	$I_{C OM} = -30 \text{ mA}$	25°C		0.15	0.2		
					Full			0.3		
$r_{on(\text{flat})} \text{ (YZP Only)}$	ON resistance flatness	1.65 V	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$	$I_{C OM} = -4 \text{ mA}$	25°C		125	130	$\Omega$	
					Full			140		
		2.3 V		$I_{C OM} = -8 \text{ mA}$	25°C		30	40		
					Full			40		
		3 V		$I_{C OM} = -24 \text{ mA}$	25°C		9	11		
					Full			12		
		4.5 V		$I_{C OM} = -30 \text{ mA}$	25°C		4	5		
					Full			6		
$r_{on(\text{flat})}$	ON resistance flatness	1.65 V	$0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_+$	$I_{C OM} = -4 \text{ mA}$	25°C		125	160	$\Omega$	
					Full			180		
		2.3 V		$I_{C OM} = -8 \text{ mA}$	25°C		30	50		
					Full			60		
		3 V		$I_{C OM} = -24 \text{ mA}$	25°C		8	13		
					Full			14		
		4.5 V		$I_{C OM} = -30 \text{ mA}$	25°C		4	5		
					Full			6		

$T_A = -40^\circ\text{C}$  to  $85^\circ\text{C}$  (unless otherwise noted)<sup>(1)</sup>

PARAMETER		TEST CONDITIONS			MIN	TYP	MAX	UNIT	
$I_{NO(OFF)}$ , $I_{NC(OFF)}$	NO, NC OFF leakage current	1.65 to 5.5 V	$V_{NO} \geq 0$ $V_{NC} \geq 0$ $V_{COM} \leq V_+$		25°C	$\pm 0.05$ $\pm 0.1$		$\mu\text{A}$	
					Full	$\pm 0.2$			
$I_{NO(ON)}$ , $I_{NC(ON)}$	NO, NC ON leakage current	1.65 to 5.5 V	$V_{NO} = V_+$ or GND $V_{NC} = V_+$ or GND $V_{COM} = \text{Open}$		25°C	$\pm 0.05$ $\pm 0.1$		$\mu\text{A}$	
					Full	$\pm 0.2$			
$I_{COM(ON)}$	COM ON leakage current	5.5 V	$V_{NO} = \text{Open}$ $V_{NC} = \text{Open}$ $V_{COM} = \text{Open}$		25°C	$\pm 0.05$ $\pm 0.1$		$\mu\text{A}$	
					Full	$\pm 0.2$			
$V_{IH}$	Input logic high			Full	$V_+ \times 0.7$	5.5		V	
$V_{IL}$	Input logic low			Full	0	$V_+ \times 0.3$	V		
$I_{IH}$	Input leakage current	1.65 to 5.5 V	5.5V or 0		25°C	0.05 $\pm 0.1$		$\mu\text{A}$	
					Full	$\pm 1$			
$I_+$	Supply current	5.5	$V_I = V_+$ or GND Switch ON or OFF		25°C	2.5 5		$\mu\text{A}$	
					Full	10			
$C_I$	Digital input capacitance	5	$V_I = V_+$ or GND		25°C	2.8		pF	
$C_{NO(OFF)}$ , $C_{NC(OFF)}$	NO, NC OFF capacitance	5	$V_{NO}$ or $V_{NC} = V_+$ or GND Switch OFF	$V_{NO}$ or $V_{NC} = V_+$ or GND Switch OFF	25°C	5.5		pF	
					Full	5.5			
$C_{NO(ON)}$ , $C_{NC(ON)}$	NO, NC ON capacitance	5	$V_{NO}$ or $V_{NC} = V_+$ or GND Switch ON		25°C	17.5		pF	
$C_{COM(ON)}$	COM ON capacitance	5	$V_{NO}$ or $V_{NC} = V_+$ or GND Switch ON		25°C	17.5		pF	

(1) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum.

## 5.6 Switching Characteristics

 $T_A = -40$  to  $+85^\circ\text{C}$ 

Parameter		$V_{CC}$	$T_A$	MIN	NOM	MAX	UNIT
$t_{ON}$	$R_L = 300\Omega$ , $C_L = 50\text{pF}$ , $V_{load} = V_{CC}$	1.8 V $\pm 0.15$ V	25°C	5	11	24	ns
			Full	5		24	
		2.5 V $\pm 0.2$ V	25°C	3.5	8	13.5	
			Full	3.5		14	
		3.3 V $\pm 0.3$ V	25°C	3.5	7	9.5	
			Full	1.5		10.5	
$t_{OFF}$	$R_L = 300\Omega$ , $C_L = 50\text{pF}$ , $V_{load} = V_{CC}$ , $V_\Delta = 0.3\text{V}$	5 V $\pm 0.5$ V	25°C	1	6	8.5	ns
			Full	1		9.5	
		1.8 V $\pm 0.15$ V	25°C	3	6	11	
			Full	3		13	
		2.5 V $\pm 0.2$ V	25°C	1	3.5	7.5	
			Full	1		7.5	
		3.3 V $\pm 0.3$ V	25°C	1	3.5	6.5	
			Full	1		7.5	
		5 V $\pm 0.5$ V	25°C	1	3.5	6.5	
			Full	1		7.5	

T<sub>A</sub> = -40 to +85°C

Parameter		V <sub>CC</sub>	T <sub>A</sub>	MIN	NOM	MAX	UNIT
T <sub>B-M</sub>	Break before make time	1.8 V ± 0.15 V	25°C	2	5.5	9	ns
			Full	2		12	
		2.5 V ± 0.2 V	25°C	2	5	7	
			Full	2		7.5	
		3.3 V ± 0.3 V	25°C	1	3	6	
			Full	1		6	
		5 V ± 0.5 V	25°C	1	2	5	
			Full	1		5	

## 5.7 (YZP Only )Switching Characteristics

T<sub>A</sub> = -40 to +85°C

Parameter		V <sub>CC</sub>	T <sub>A</sub>	MIN	NOM	MAX	UNIT
t <sub>ON</sub>	R <sub>L</sub> = 300Ω, C <sub>L</sub> = 50pF, V <sub>load</sub> = V <sub>CC</sub>	1.8 V ± 0.15 V	25°C	5	15	24	ns
			Full	7		24	
		2.5 V ± 0.2 V	25°C	5	8	13.5	
			Full	3.5		14	
		3.3 V ± 0.3 V	25°C	3.5	7	9.5	
			Full	1.5		10.5	
		5 V ± 0.5 V	25°C	1	6	8.5	
			Full	1		9.5	
t <sub>OFF</sub>	R <sub>L</sub> = 300Ω, C <sub>L</sub> = 50pF, V <sub>load</sub> = V <sub>CC</sub> , V <sub>Δ</sub> = 0.3V	1.8 V ± 0.15 V	25°C	1	3.5	6.5	ns
			Full	1		7.5	
		2.5 V ± 0.2 V	25°C	1	3.5	6.5	
			Full	1		7.5	
		3.3 V ± 0.3 V	25°C	1	3.5	6.5	
			Full	1		7.5	
		5 V ± 0.5 V	25°C	1	3.5	6.5	
			Full	1		7.5	
T <sub>B-M</sub>	Break before make time	1.8 V ± 0.15 V	25°C	5.5	7.5	9	ns
			Full	5.2		12	
		2.5 V ± 0.2 V	25°C	3.5	5	7	
			Full	3		7.5	
		3.3 V ± 0.3 V	25°C	2.5	3	5	
			Full	2		5	
		5 V ± 0.5 V	25°C	1.8	2	3	
			Full	1.8		3.5	

## 5.8 Analog Channel Specifications

over operating free-air temperature range (unless otherwise noted)

Parameter	TEST CONDITIONS	V <sub>CC</sub>	MIN	NOM	MAX	UNIT
Frequency response (switch on) <sup>(1)</sup>	R <sub>L</sub> = 50 Ω, f <sub>in</sub> = sine wave	1.65 V		300		MHz
		2.3 V		300		
		3 V		300		
		4.5 V		300		

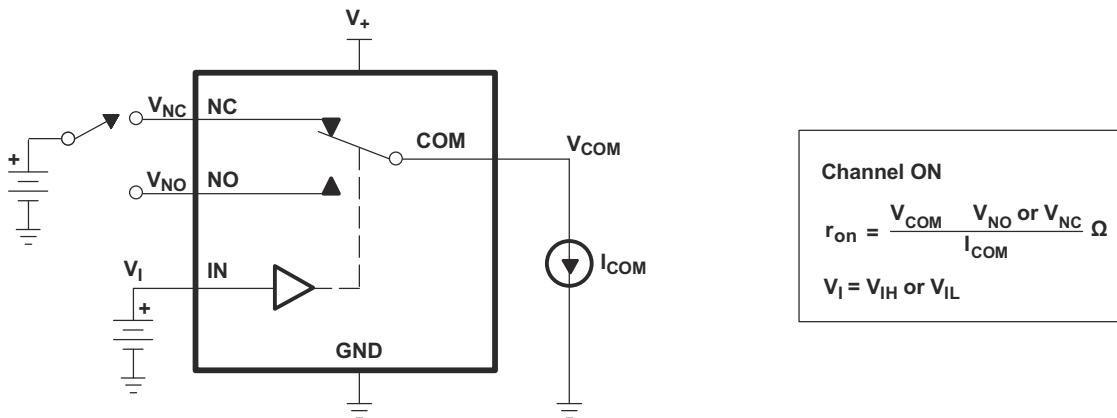
over operating free-air temperature range (unless otherwise noted)

Parameter	TEST CONDITIONS	$V_{CC}$	MIN	NOM	MAX	UNIT
Crosstalk (between switches) (YZP Only) <sup>(2)</sup>	$R_L = 50 \Omega$ , $f_{in} = 10 \text{ MHz}$ (sine wave)	1.65 V		-66		dB
		2.3 V		-66		
		3 V		-66		
		4.5 V		-66		
Crosstalk (between switches) <sup>(2)</sup>	$R_L = 50 \Omega$ , $f_{in} = 10 \text{ MHz}$ (sine wave)	1.65 V		-60		dB
		2.3 V		-60		
		3 V		-60		
		4.5 V		-60		
Feed through attenuation (switch off) (YZP Only) <sup>(2)</sup>	$C_L = 5 \text{ pF}$ , $R_L = 50 \Omega$ , $f_{in} = 10 \text{ MHz}$ (sine wave)	1.65 V		-65		dB
		2.3 V		-65		
		3 V		-65		
		4.5 V		-65		
Feed through attenuation (switch off) <sup>(2)</sup>	$C_L = 5 \text{ pF}$ , $R_L = 50 \Omega$ , $f_{in} = 10 \text{ MHz}$ (sine wave)	1.65 V		-57		dB
		2.3 V		-57		
		3 V		-57		
		4.5 V		-57		
Charge injection	$C_L = 0.1 \text{ nF}$ , $R_L = 1 \text{ M}\Omega$	1.65 V		1		pC
		2.3 V		2		
		3.3 V		3		
		5 V		7		
Total harmonic distortion (YZP Only)	$V_I = 1.4 \text{ V}_{pp}$ , $V_{bias} = V_{CC}/2$ , $R_L = 10\text{k}\Omega$ , $f_{in} = 600 \text{ Hz to } 20\text{kHz}$ (sine wave)	1.65 V		0.015		%
Total harmonic distortion	$V_I = 1.4 \text{ V}_{pp}$ , $V_{bias} = V_{CC}/2$ , $R_L = 10\text{k}\Omega$ , $f_{in} = 600 \text{ Hz to } 20\text{kHz}$ (sine wave)	1.65 V		0.5		%
	$V_I = 2.0 \text{ V}_{pp}$ , $V_{bias} = V_{CC}/2$ , $R_L = 10\text{k}\Omega$ , $f_{in} = 600 \text{ Hz to } 20\text{kHz}$ (sine wave)	2.3 V		0.025		
	$V_I = 2.5 \text{ V}_{pp}$ , $V_{bias} = V_{CC}/2$ , $R_L = 10\text{k}\Omega$ , $f_{in} = 600 \text{ Hz to } 20\text{kHz}$ (sine wave)	3 V		0.015		
	$V_I = 4.0 \text{ V}_{pp}$ , $V_{bias} = V_{CC}/2$ , $R_L = 10\text{k}\Omega$ , $f_{in} = 600 \text{ Hz to } 20\text{kHz}$ (sine wave)	4.5 V		0.01		

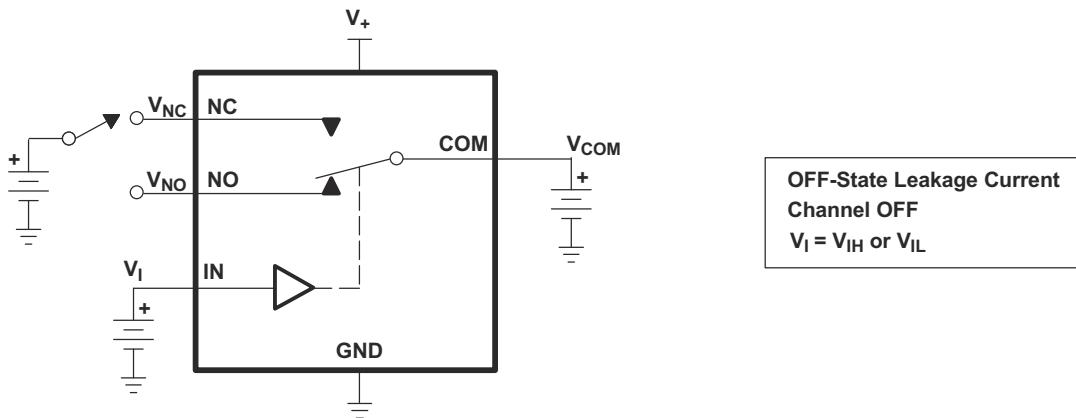
(1) Set fin to 0 dBm and provide a bias of 0.4 V. Increase fin frequency until the gain is 3 dB below the insertion loss.

(2) Set fin to 0 dBm and provide a bias of 0.4 V.

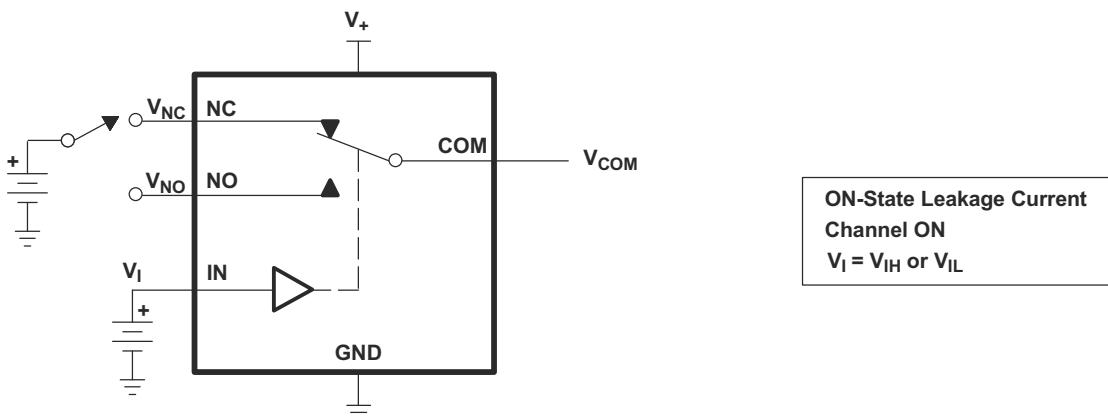
## 6 Parameter Measurement Information



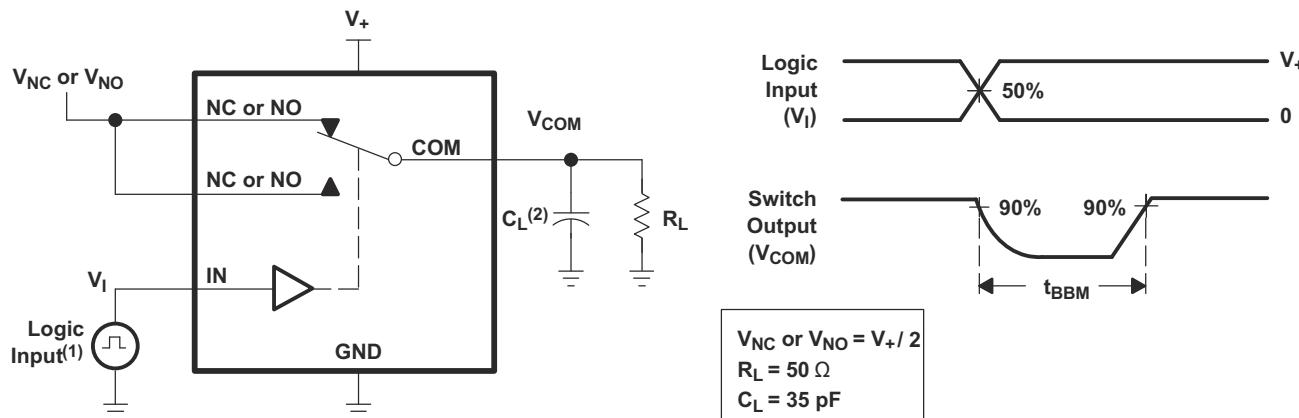
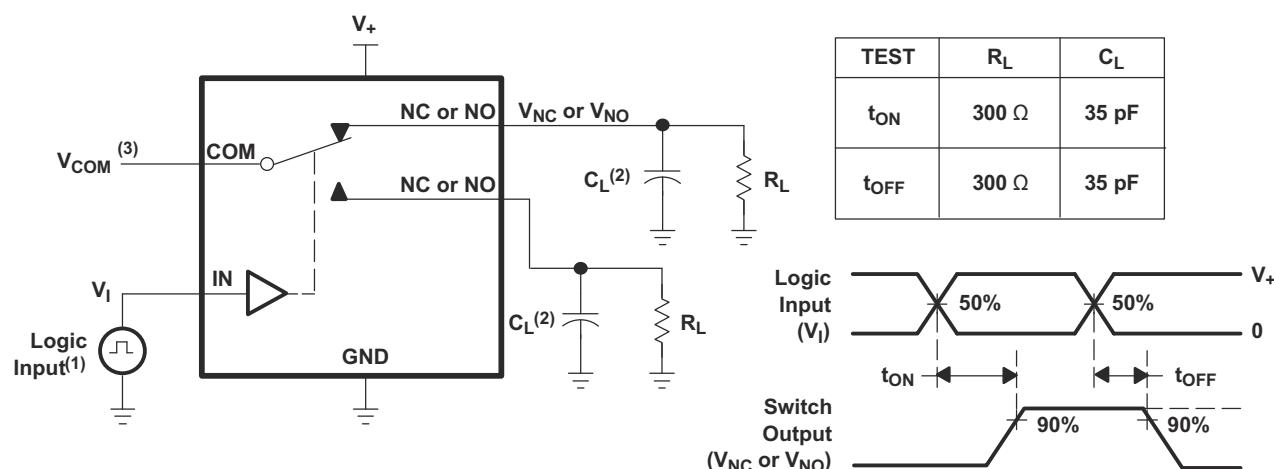
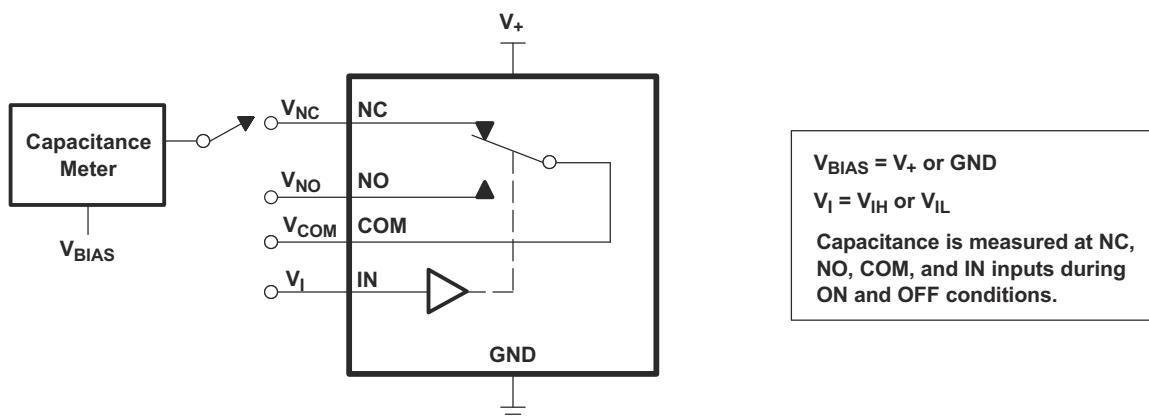
**Figure 6-1. ON-State Resistance ( $r_{on}$ )**

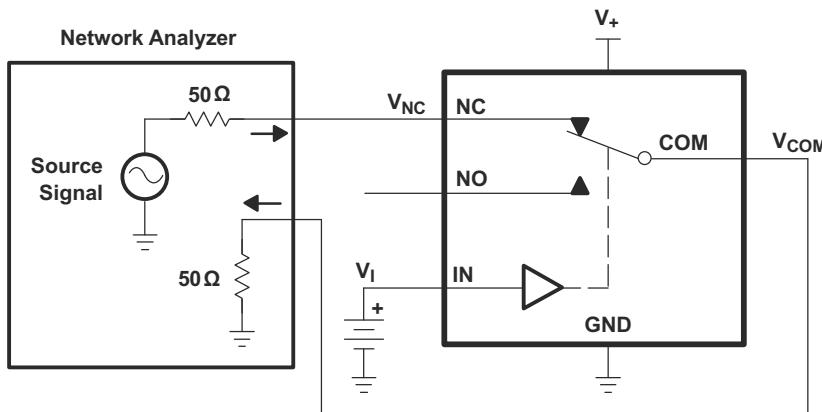


**Figure 6-2. OFF-State Leakage Current ( $I_{NC(OFF)}$ ,  $I_{NO(OFF)}$ )**



**Figure 6-3. ON-State Leakage Current ( $I_{COM(ON)}$ ,  $I_{NC(ON)}$ ,  $I_{NO(ON)}$ )**

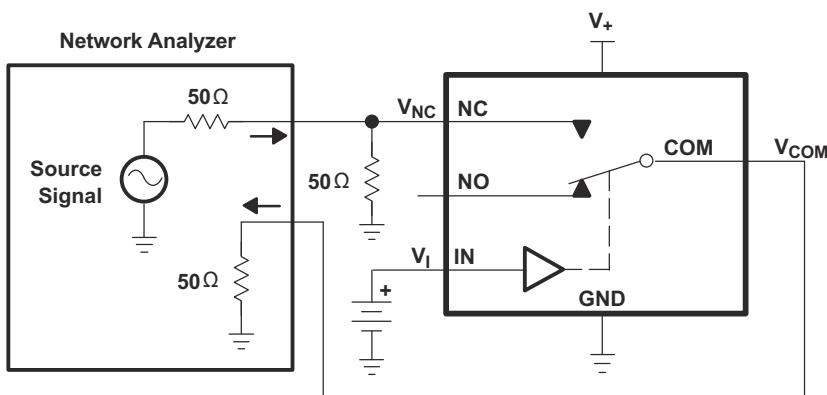




Channel ON: NC to COM  
 $V_I = V_+$  or GND

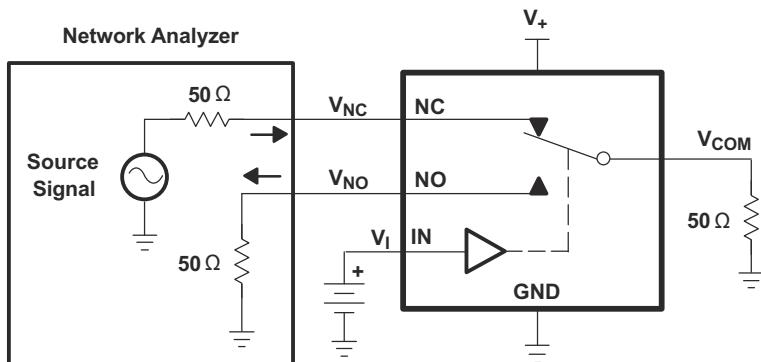
Network Analyzer Setup  
 Source Power = 0 dBm  
 (632-mV P-P at 50-Ω load)  
 DC Bias = 350 mV

Figure 6-7. Bandwidth (BW)



Channel OFF: NC to COM  
 $V_I = V_+$  or GND

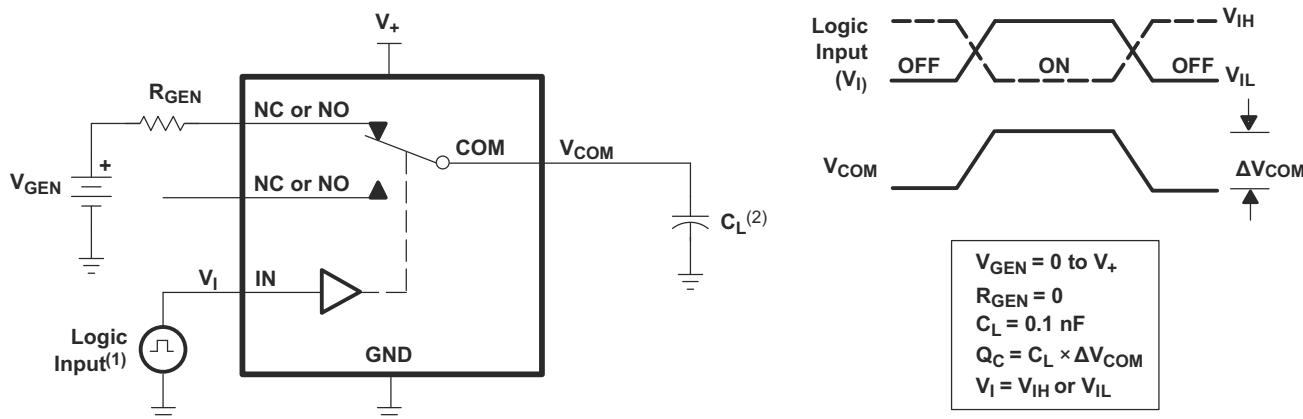
Network Analyzer Setup  
 Source Power = 0 dBm  
 (632-mV P-P at 50-Ω load)  
 DC Bias = 350 mV

Figure 6-8. OFF Isolation ( $O_{ISO}$ )

Channel ON: NC to COM  
 Channel OFF: NO to COM  
 $V_I = V_+$  or GND

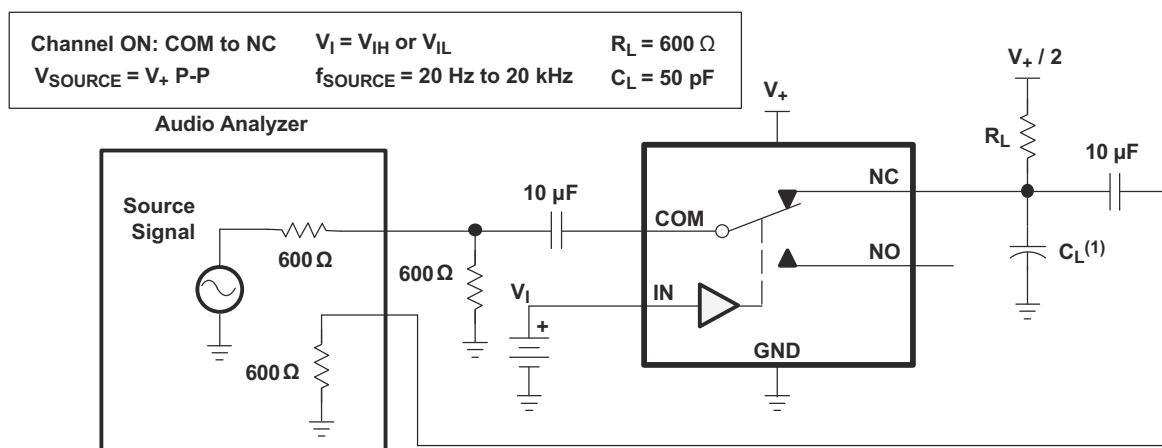
Network Analyzer Setup  
 Source Power = 0 dBm  
 (632-mV P-P at 50-Ω load)  
 DC Bias = 350 mV

Figure 6-9. Crosstalk ( $X_{TALK}$ )



- A. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ ,  $t_r < 5 \text{ ns}$ ,  $t_f < 5 \text{ ns}$ .
- B.  $C_L$  includes probe and jig capacitance.

**Figure 6-10. Charge Injection ( $Q_C$ )**



A.  $C_I$  includes probe and jig capacitance.

**Figure 6-11. Total Harmonic Distortion (THD)**

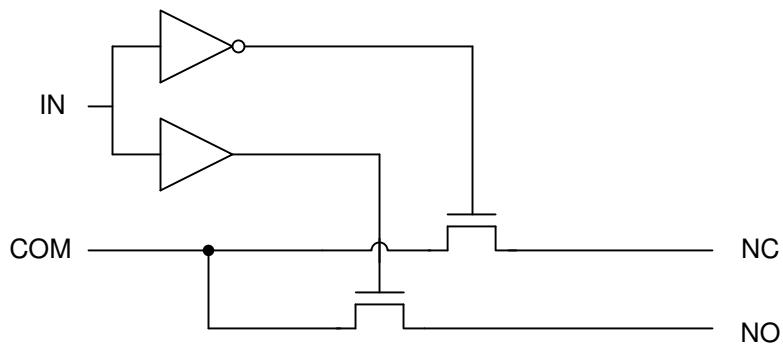
## 7 Detailed Description

### 7.1 Overview

The TS5A3157 is a single-pole-double-throw (SPDT) solid-state analog switch. The TS5A3157, like all analog switches, is bidirectional. When powered on, each COM pin is connected to the NC pin. For this device, NC stands for *normally closed* and NO stands for *normally open*. If IN is low, COM is connected to NC. If IN is high, COM is connected to NO.

The TS5A3157 is a break-before-make switch. This means that during switching, a connection is broken before a new connection is established. The NC and NO pins are never connected to each other.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

The low ON-state resistance, ON-state resistance matching, and charge injection in the TS5A3157 make this switch an excellent choice for analog signals that require minimal distortion. In addition, the low THD allows audio signals to be preserved more clearly as they pass through the device.

The 1.65V to 5.5V operation allows compatibility with more logic levels, and the bidirectional I/Os can pass analog signals from 0V to  $V_+$  with low distortion. The control inputs are 5V tolerant, allowing control signals to be present without  $V_{CC}$ .

### 7.4 Device Functional Modes

Table 7-1. Function Table

IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO
L	ON	OFF
H	OFF	ON

## 8 Application and Implementation

### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The TS5A3157 can be used in a variety of customer systems. The TS5A3157 can be used anywhere multiple analog or digital signals must be selected to pass across a single line.

### 8.2 Typical Application

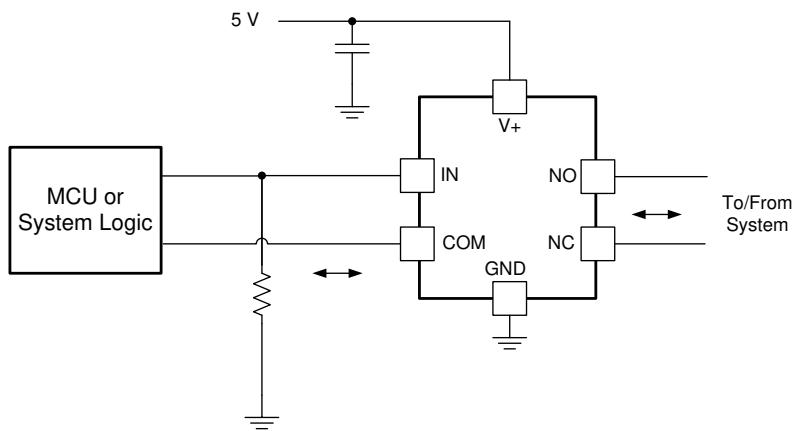


Figure 8-1. System Schematic for TS5A3157

#### 8.2.1 Design Requirements

In this particular application,  $V_+$  was 1.8V, although  $V_+$  is allowed to be any voltage specified in [Section 5.4](#). A decoupling capacitor is recommended on the  $V_+$  pin. See [Section 8.3](#) for more details.

#### 8.2.2 Detailed Design Procedure

In this application, IN is, by default, pulled low to GND. Choose the resistor size based on the current driving strength of the GPIO, the desired power consumption, and the switching frequency (if applicable). If the GPIO is open-drain, use pullup resistors instead.

### 8.2.3 Application Curve

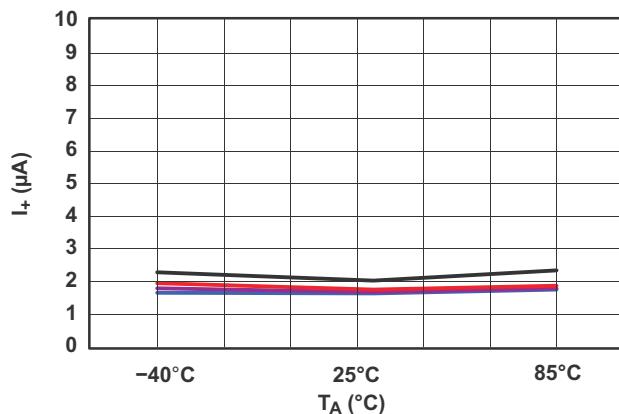


Figure 8-2. Power-Supply Current vs Temperature (V<sub>+</sub> = 5V)

## 8.3 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the [Section 5.4](#).

Each V<sub>CC</sub> terminal should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, a 0.1μF bypass capacitor is recommended. If there are multiple pins labeled V<sub>CC</sub>, then a 0.01μF or 0.022μF capacitor is recommended for each V<sub>CC</sub> because the V<sub>CC</sub> pins will be tied together internally. For devices with dual supply pins operating at different voltages, for example V<sub>CC</sub> and V<sub>DD</sub>, a 0.1μF bypass capacitor is recommended for each supply pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. 0.1μF and 1μF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

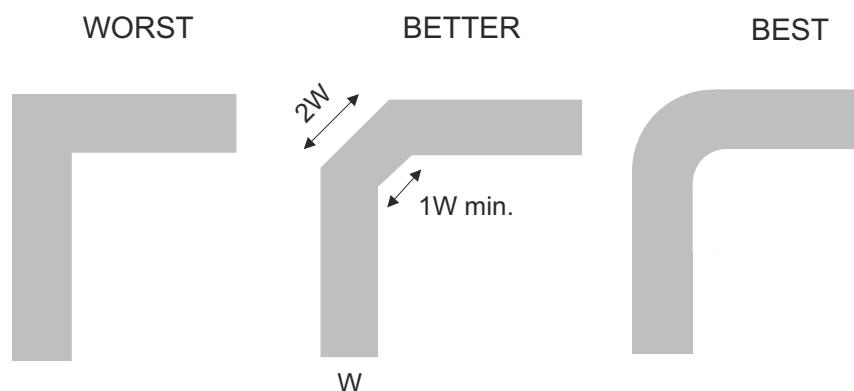
## 8.4 Layout

### 8.4.1 Layout Guidelines

Reflections and matching are closely related to loop antenna theory, but different enough to warrant their own discussion. When a PCB trace turns a corner at a 90° angle, a reflection can occur. This is primarily due to the change of width of the trace. At the apex of the turn, the trace width is increased to 1.414 times its width. This upsets the transmission line characteristics, especially the distributed capacitance and self-inductance of the trace — resulting in the reflection. It is a given that not all PCB traces can be straight, and so they will have to turn corners. Below figure shows progressively better techniques of rounding corners. Only the last example maintains constant trace width and minimizes reflections.

Unused switch I/Os, such as NO, NC, and COM, can be left floating or tied to GND. However, the IN pin must be driven high or low. Due to partial transistor turnon when control inputs are at threshold levels, floating control inputs can cause increased I<sub>CC</sub> or unknown switch selection states.

#### 8.4.2 Layout Example



**Figure 8-3. Trace Example**

## 9 Device and Documentation Support

### 9.1 Device Support

#### 9.1.1 Device Nomenclature

**Table 9-1. Parameter Description**

SYMBOL	DESCRIPTION
$V_{COM}$	Voltage at COM
$V_{NC}$	Voltage at NC
$V_{NO}$	Voltage at NO
$r_{on}$	Resistance between COM and NC or COM and NO ports when the channel is ON
$\Delta r_{on}$	Difference of $r_{on}$ between channels in a specific device
$r_{on(flat)}$	Difference between the maximum and minimum value of $r_{on}$ in a channel over the specified range of conditions
$I_{NC(OFF)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state
$I_{NO(OFF)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
$I_{NC(ON)}$	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) open
$I_{NO(ON)}$	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
$I_{COM(ON)}$	Leakage current measured at the COM port, with the corresponding channel (COM to NO or COM to NC) in the ON state and the output (NC or NO) open
$V_{IH}$	Minimum input voltage for logic high for the control input (IN)
$V_{IL}$	Maximum input voltage for logic low for the control input (IN)
$V_I$	Voltage at the control input (IN)
$I_{IH}, I_{IL}$	Leakage current measured at the control input (IN)
$t_{ON}$	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning ON.
$t_{OFF}$	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM, NC, or NO) signal when the switch is turning OFF.
$t_{BBM}$	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.
$Q_C$	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NO, or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$ . $C_L$ is the load capacitance and $\Delta V_{COM}$ is the change in analog output voltage.
$C_{NC(OFF)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF
$C_{NO(OFF)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
$C_{NC(ON)}$	Capacitance at the NC port when the corresponding channel (NC to COM) is ON
$C_{NO(ON)}$	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
$C_{COM(ON)}$	Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON
$C_I$	Capacitance of control input (IN)
$O_{ISO}$	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.
$X_{TALK}$	Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured in a specific frequency and in dB.
$BW$	Bandwidth of the switch. This is the frequency where the gain of an ON channel is $-3$ dB below the DC gain.
$THD$	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of fundamental harmonic.
$I_+$	Static power-supply current with the control (IN) pin at $V_+$ or GND

## 9.2 Documentation Support

### 9.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, [Implications of Slow or Floating CMOS Inputs](#)

## 9.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](#). Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 9.4 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

## 9.5 Trademarks

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## 9.6 Electrostatic Discharge Caution

 This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 9.7 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (May 2025) to Revision D (July 2025)	Page
• Separated relevant DBV and DCK specifications from other packages.....	<a href="#">4</a>

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<b>Changes from Revision B (May 2015) to Revision C (May 2025)</b>	<b>Page</b>
• Updated the numbering format for tables, figures, and cross-references throughout the document.....	1
• Updated the <i>Package Information</i> table to include package lead size.....	1
• Updated Ron and flatness values.....	6
• Included all voltage ranges into the same table and updated conditions accordingly.....	6
• Updated enable timing for 1.8V, and 2.5V.....	7
• Updated disable timing for 1.8V, and 2.5V.....	7
• Updated bbm timing for 1.8V, 2.5V, 3.3V, and 5V.....	7

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<b>Changes from Revision A (September 2004) to Revision B (May 2015)</b>	<b>Page</b>
• Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes, Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	1
• Removed <i>Ordering Information</i> table. ....	1

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<b>Changes from Revision * (August 2004) to Revision A (September 2004)</b>	<b>Page</b>
• Updated document to new TI data sheet format - no specification changes. ....	1

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## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
<a href="#">TS5A3157DBVR</a>	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	(3HVH, JC5R)
TS5A3157DBVR.A	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(3HVH, JC5R)
TS5A3157DBVR.B	Active	Production	SOT-23 (DBV)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(3HVH, JC5R)
<a href="#">TS5A3157DCKR</a>	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 85	(JC5, JCF, JCJ, JC R)
TS5A3157DCKR.A	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(JC5, JCF, JCJ, JC R)
TS5A3157DCKR.B	Active	Production	SC70 (DCK)   6	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	(JC5, JCF, JCJ, JC R)
<a href="#">TS5A3157YZPR</a>	Active	Production	DSBGA (YZP)   6	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	JCN
TS5A3157YZPR.B	Active	Production	DSBGA (YZP)   6	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	JCN

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

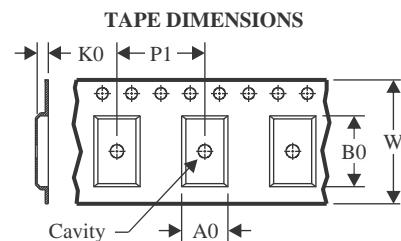
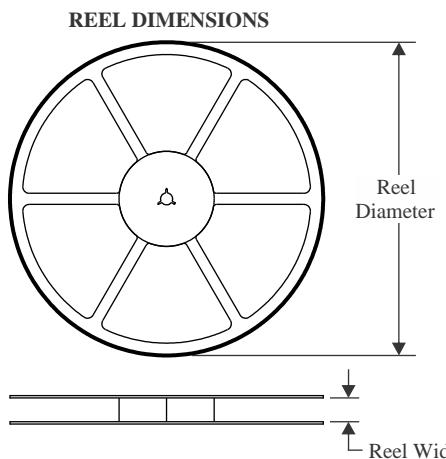
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

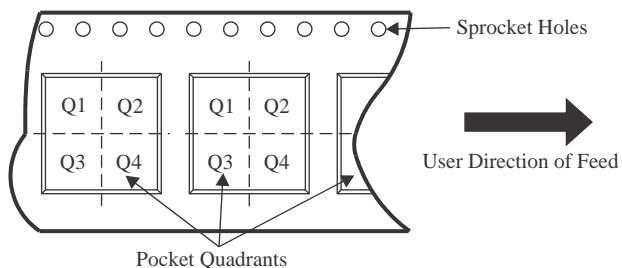
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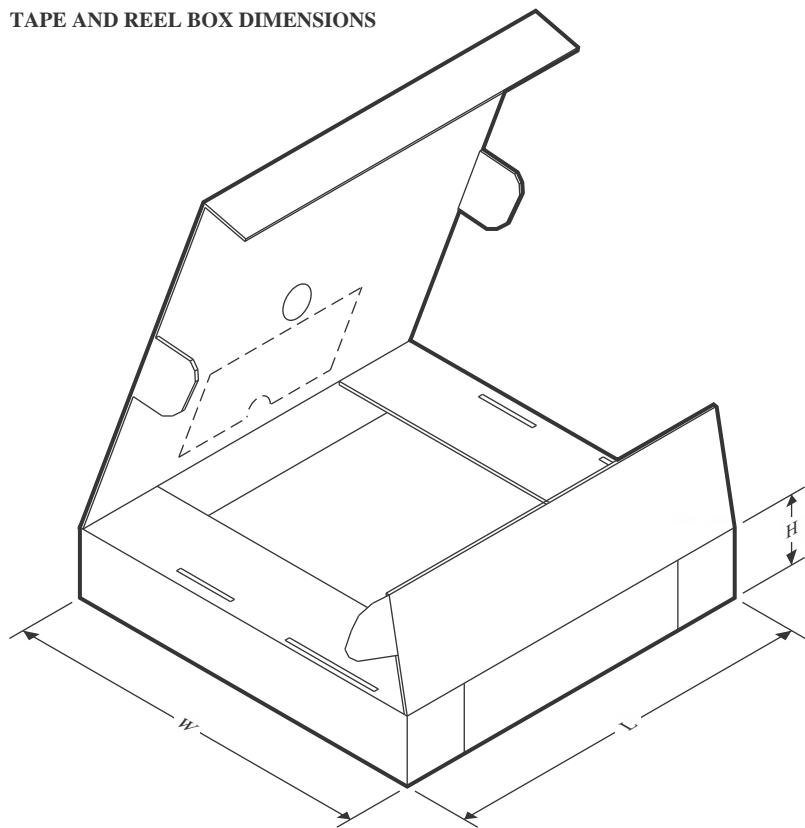
**TAPE AND REEL INFORMATION**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A3157DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS5A3157DBVR	SOT-23	DBV	6	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TS5A3157DCKR	SC70	DCK	6	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TS5A3157YZPR	DSBGA	YZP	6	3000	178.0	9.2	1.02	1.52	0.63	4.0	8.0	Q1

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A3157DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TS5A3157DBVR	SOT-23	DBV	6	3000	210.0	185.0	35.0
TS5A3157DCKR	SC70	DCK	6	3000	180.0	180.0	18.0
TS5A3157YZPR	DSBGA	YZP	6	3000	220.0	220.0	35.0

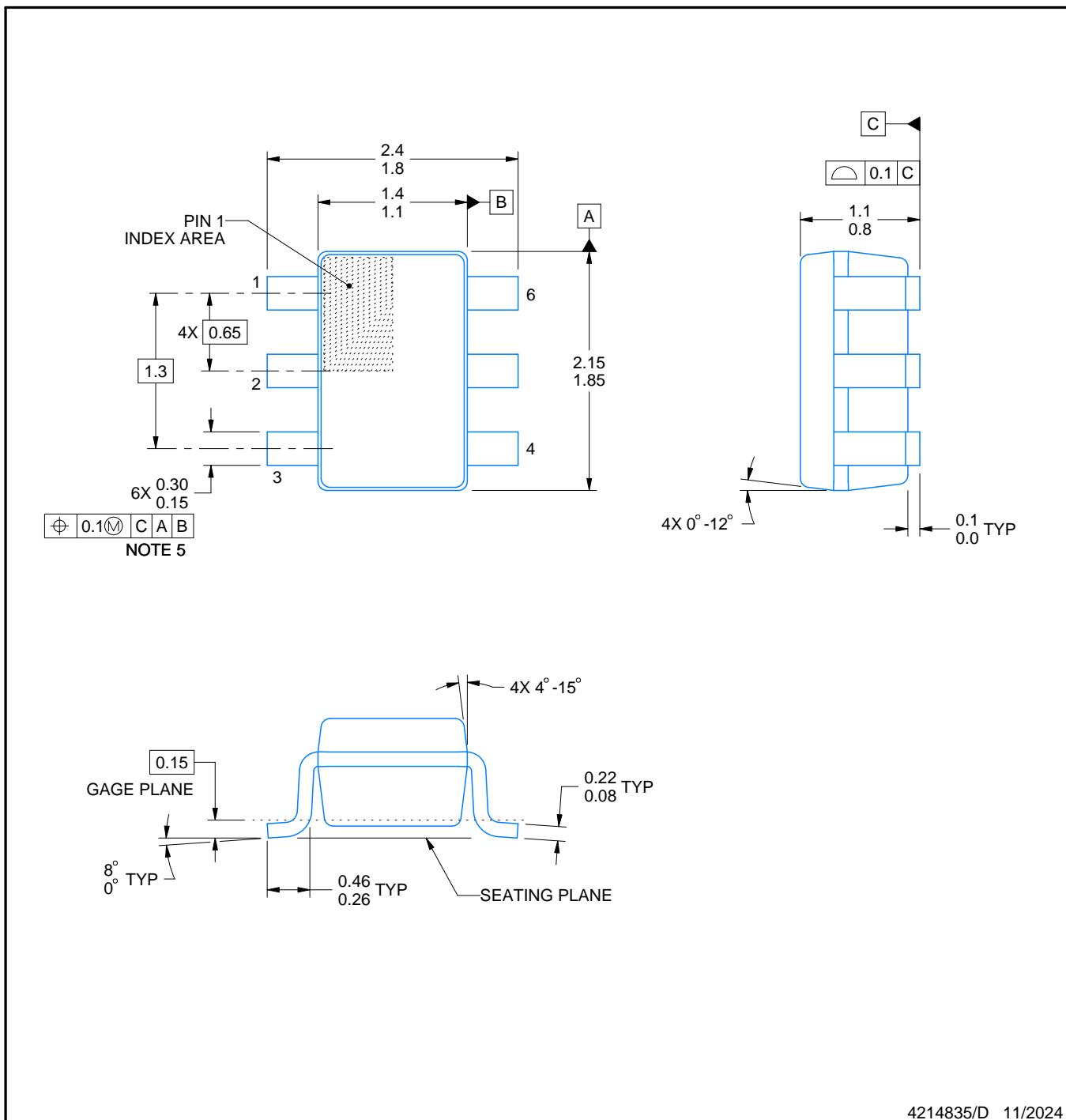
# PACKAGE OUTLINE

DCK0006A



SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



## NOTES:

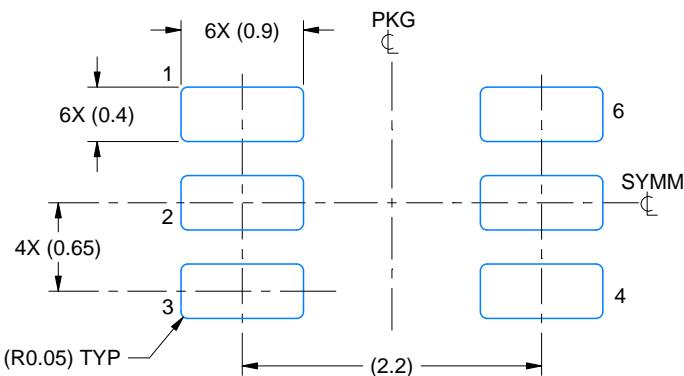
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
4. Falls within JEDEC MO-203 variation AB.

# EXAMPLE BOARD LAYOUT

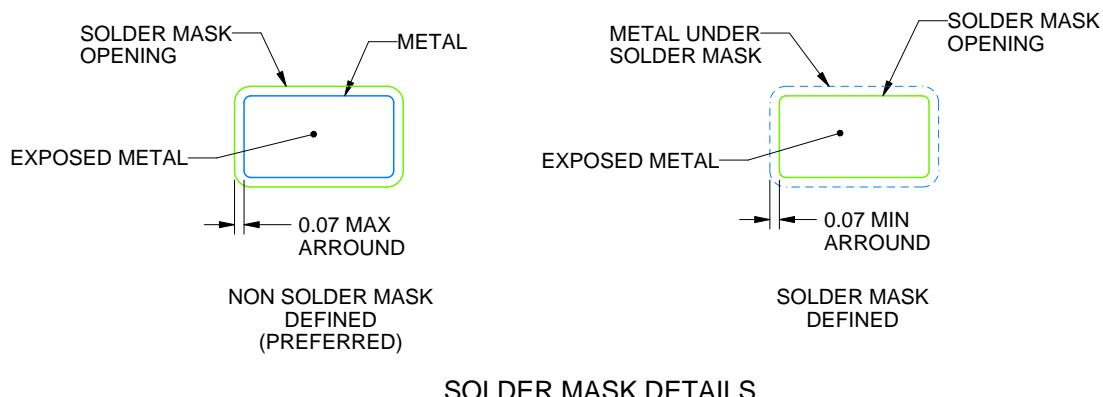
DCK0006A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



4214835/D 11/2024

NOTES: (continued)

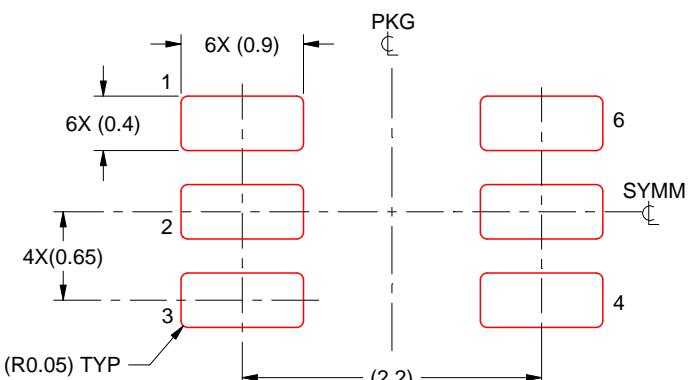
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DCK0006A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:18X

4214835/D 11/2024

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

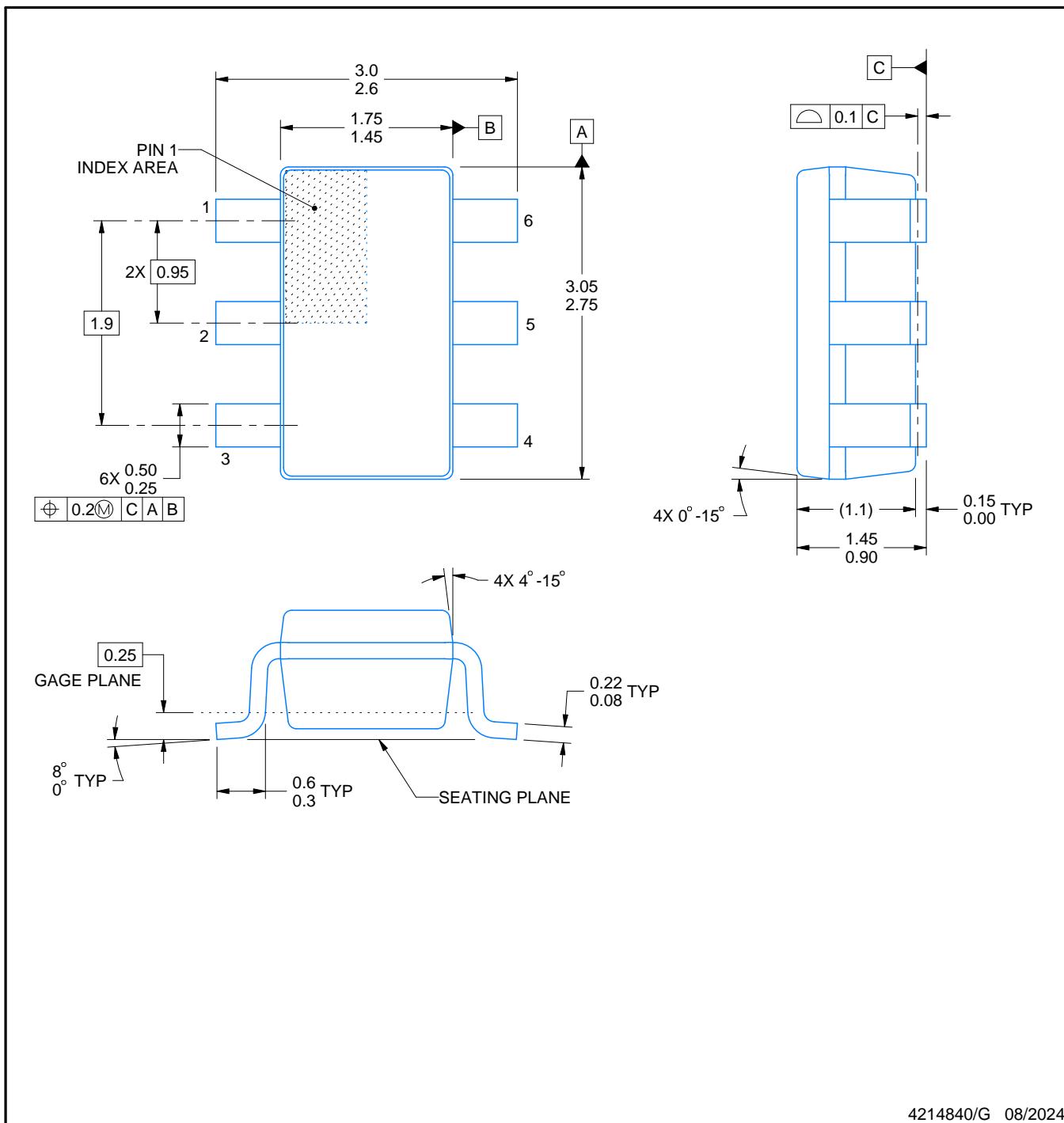
# PACKAGE OUTLINE

DBV0006A



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



## NOTES:

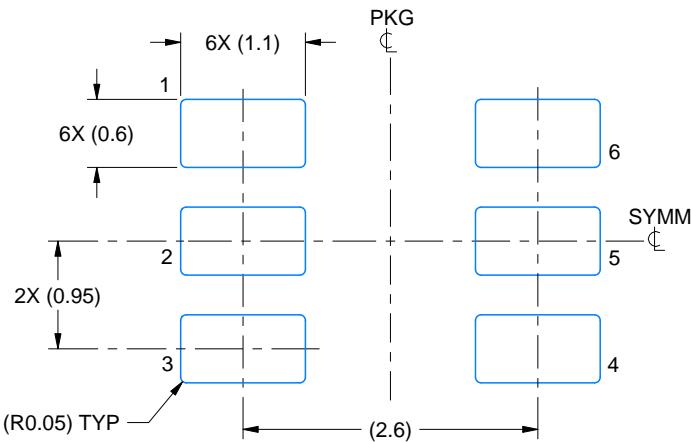
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.25 per side.
4. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
5. Reference JEDEC MO-178.

# EXAMPLE BOARD LAYOUT

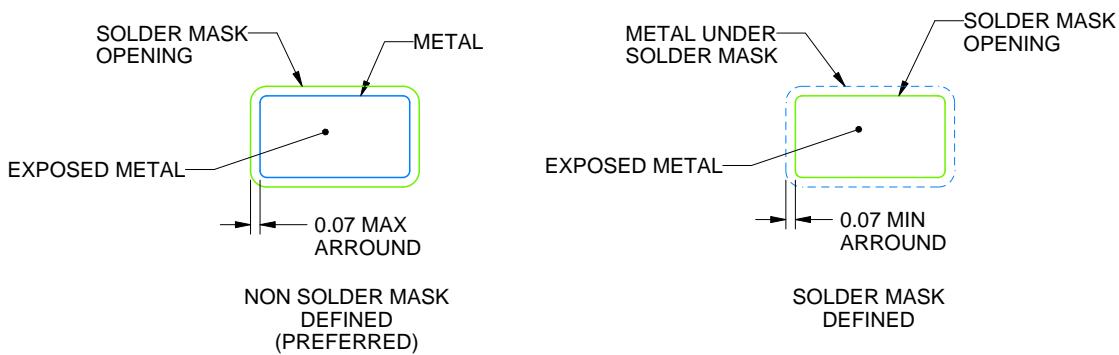
DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS

4214840/G 08/2024

NOTES: (continued)

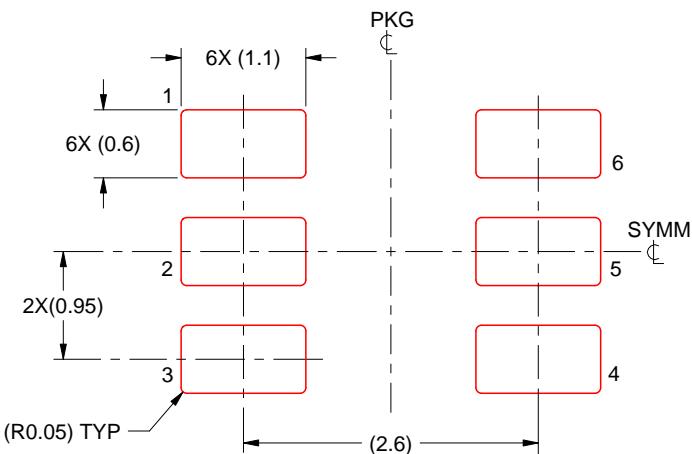
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DBV0006A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

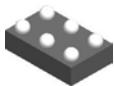


SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

4214840/G 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

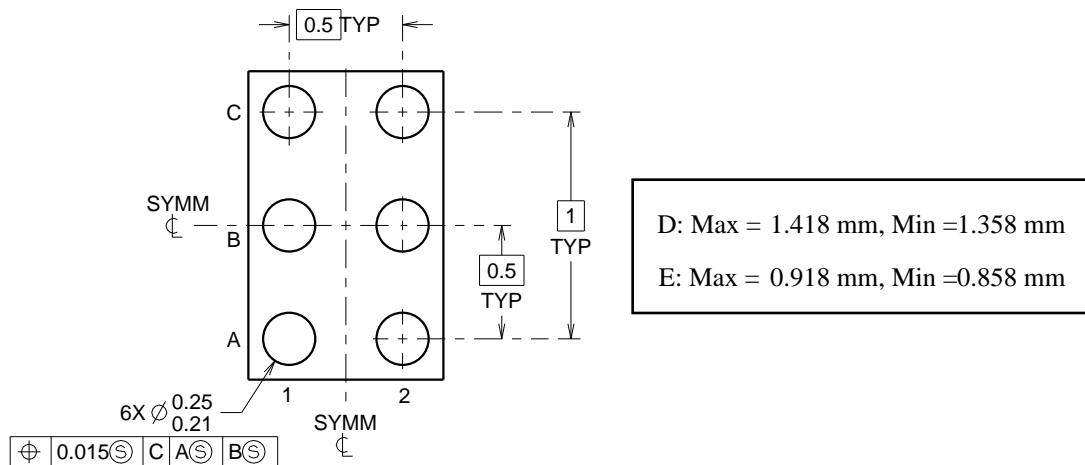
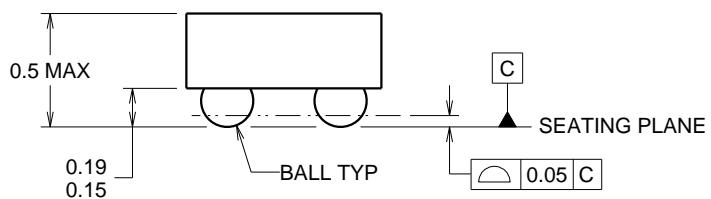
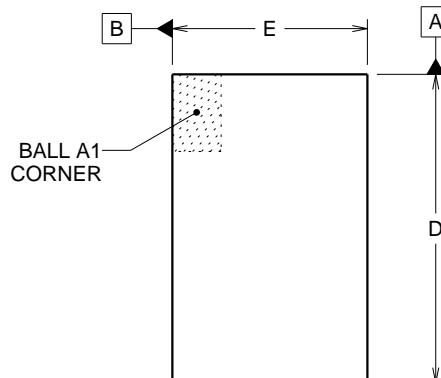


# PACKAGE OUTLINE

YZP0006

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



4219524/A 06/2014

NOTES:

NanoFree is a trademark of Texas Instruments.

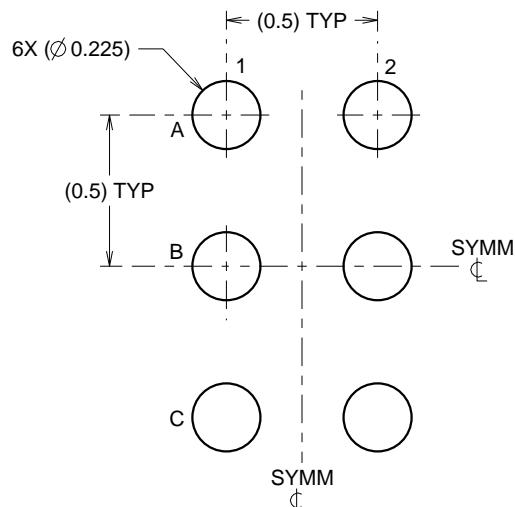
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

# EXAMPLE BOARD LAYOUT

YZP0006

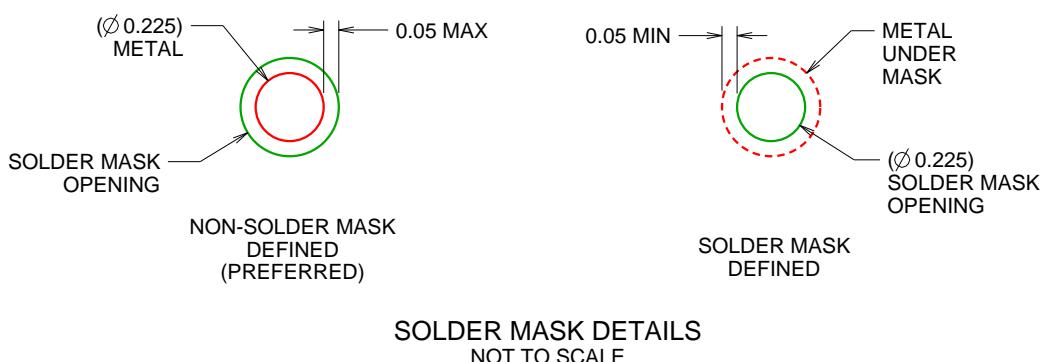
DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



LAND PATTERN EXAMPLE

SCALE:40X



SOLDER MASK DETAILS  
NOT TO SCALE

4219524/A 06/2014

NOTES: (continued)

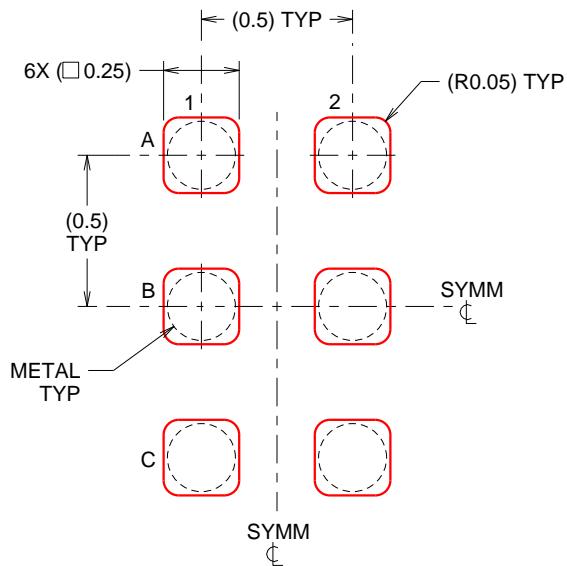
4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SBVA017 ([www.ti.com/lit/sbva017](http://www.ti.com/lit/sbva017)).

# EXAMPLE STENCIL DESIGN

YZP0006

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:40X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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